NSN 5961-00-765-2829

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-765-2829 **Inclosure Material:** Metal all transistor **Overall Length:** 0.260 inches all transistor **Terminal Length:** 1.500 inches all transistor **Internal Configuration:** Junction contact all transistor **Internal Junction Configuration:** Pnp all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal all transistor **Terminal Circle Diameter:** 0.200 inches all transistor **Semiconductor Material:** Germanium all transistor Voltage Rating In Volts Per Characteristic: -25.0 collector to base voltage/static/emitter open all transistor and -25.0 collector-to-emitter, resistance between base and emitter all transistor and -15.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter all transistor and 150.0 static forward current transfer ratio, common-emitter all transistor **Terminal Type And Quantity:** 3 uninsulated wire lead all transistor Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig:

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